

# Santa Clara University

## Department of Electrical and Computer Engineering

No. \_\_\_\_\_ DAREN LIU

Submitted on: 11/11/20

Name (please print)

• Include this page with Homework

• Write Name and Page Number on each page

ELEN 153  
Fall 2020

Problem Set #6

Due: 11-12-2020, Thursday, 12:00 pm

1. An nFET with Channel width and length of  $6\ \mu\text{m}$  and  $45\ \text{nm}$ , respectively, is built in a process where  $\kappa'_n = 158\ \mu\text{A}/\text{V}^2$  and  $V_{Tn} = 0.75\ \text{V}$ . The voltages are set to a value of  $V_{GSn} = V_{DSn} = V_{DD} = 3.3\ \text{V}$ .

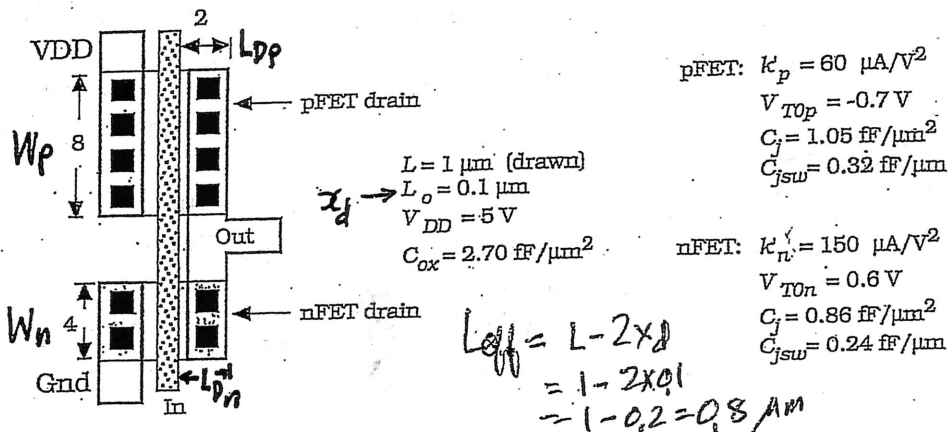
- (15) a) Is the transistor saturated or non-saturated?  
b) Calculate the drain-source resistance using the appropriate relationship for the transistor.  
c) Compare your value in b) with that found using relationship (6.71) Page 214, with a value of  $\eta = 1$ .

2. Consider the NOT gate (see below) when an external load of  $C_L = 72\ \text{fF}$  is connected to the output. Note that the electrical channel length is  $L = 0.8\ \mu\text{m}$ .

- (30) a) Calculate the input capacitance,  $C_{in} = C_{Gp} + C_{Gn}$  of the circuit.  
b) Calculate the FET capacitance,  $C_{FET} = C_{Dp} + C_{Dn}$  and the Output capacitance  $C_{out} = C_{FET} + C_L$ .  
 $C_{Dp} = C_{GDP} + C_{DBp} = (C_{gd} + C_{gdo}) + C_{Ddiff}$ , where  $C_{Ddiff} = C_{j0}W_pL_{Dp} + C_{jsw}(W_p + 2L_{Dp})$

3. An nFET has a gate oxide with a thickness of  $t_{ox} = 24\ \text{nm}$ . The p-type bulk region is doped with Boron at a density of  $N_a = 4 \times 10^{15}/\text{cm}^3$ . Channel width =  $4\ \mu\text{m}$ ; Channel length =  $25\ \text{nm}$ .

- (30) a) Calculate the device No body-bias threshold voltage.  
b) Calculate the body bias coefficient  $\gamma$ .  
c) What is the device threshold voltage if a body bias voltage of  $V_{SBn} = 1.2\ \text{V}$  is applied.  
d) Calculate the drain current with bias voltages of  $V_{GSn} = 2.3\ \text{V}$ ,  $V_{DSn} = 1.9\ \text{V}$  applied to the device in c). Use mobility value from mobility chart.



$$1) a) V_{sat} = V_{GSn} - V_T = 3.3 - 0.75 = 2.55$$

$$V_{DSn} = 3.3 > 2.55, \text{ saturated}$$

$$b) R_n = \frac{2 V_{DSn}}{\beta_n (V_{sat})^2} = \frac{2(3.3)}{(158)(\frac{6000}{45})(2.55)^2} = 48.18 \Omega$$

$$c) R_n = \frac{n}{\beta_n (V_{DD} - V_{Tn})} = \frac{1}{(158)(\frac{6000}{45})(3.3 - 0.75)} = 18.62 \Omega$$

$$2) a) C_{in} = C_{GP} + C_{GN} = C_{ox} L_{eff} (W_p + W_n)$$

$$= (2.7)(1)(8 + 4) = 32.44 \text{ fF}$$

$$b) C_{DP} = C_{GDP} + C_{DDP} = C_{ox}(W_p)(\frac{1}{2}L_{eff} + x_d) + C_{jo} W_p L_{DP}$$

$$+ C_{jwo}(W_p + 2L_{DP})$$

$$= (2.7)(8)(\frac{1}{2}(0.8) + 0.1) + (1.05)(8)(2) + (0.32)(8 + 2(2))$$

$$= 31.44 \text{ fF}$$

$$C_{DN} = C_{ox}(W_n)(\frac{1}{2}L_{eff} + x_d) + C_{jon}(W_n)(L_{DN}) + C_{jswn}(W_n + 2L_{DN})$$

$$= (2.7)(4)(\frac{1}{2}(0.8) + 0.1) + (0.86)(4)(2) + (0.24)(4 + 2(2))$$

$$= 14.2 \text{ fF}$$

$$C_{FET} = C_{DN} + C_{DP} = 14.2 + 31.44 = 45.64 \text{ fF}$$

$$C_{out} = C_{FET} + C_L = 45.64 + 72 = 117.64 \text{ fF}$$

$$3) a) \phi_F = \frac{kT}{q} \ln\left(\frac{N_A}{n_i}\right) = \frac{(1.381 \cdot 10^{-23})(300)}{1.602 \cdot 10^{-19}} \ln\left(\frac{4 \cdot 10^{15}}{1.45 \cdot 10^{10}}\right)$$

$$= 0.324 \text{ J/C}$$

$$C_{ox} = \frac{\epsilon_{ox}}{t_{ox}} = \frac{3.9(9.854 \cdot 10^{-14})}{24(\frac{1 \text{ cm}}{10^7 \text{ nm}})} = 1.44 \cdot 10^{-7} \text{ F/cm}^2$$

$$\begin{aligned}
 V_{T0n} &= \frac{1}{C_{ox}} \sqrt{2q\epsilon_{si}N_n(2\phi_F)} + 2\phi_F \\
 &= \frac{1}{1.44 \cdot 10^{-7}} \sqrt{2(1.602 \cdot 10^{-19})(11.7 \cdot 8.854 \cdot 10^{-14})(4 \cdot 10^{15})(2 \cdot 0.324)} \\
 &\quad + 2(0.324) \\
 &= 0.852 \text{ V}
 \end{aligned}$$

$$\begin{aligned}
 b) \quad \gamma &= \frac{\sqrt{2q\epsilon_{si}N_n}}{C_{ox}} = \frac{\sqrt{2(1.602 \cdot 10^{-19})(11.7 \cdot 8.854 \cdot 10^{-14})(4 \cdot 10^{15})}}{1.44 \cdot 10^{-7}} \\
 &= 0.253 \text{ V}^{\frac{1}{2}}
 \end{aligned}$$

$$\begin{aligned}
 c) \quad V_{Tn} &= V_{T0n} + \gamma(\sqrt{2\phi_F + V_{SBn}} - \sqrt{2\phi_F}) \\
 &= 0.852 + (2.53)(\sqrt{2(0.324) + 1.2} - \sqrt{2(0.324)}) \\
 &= 0.992 \text{ V}
 \end{aligned}$$

$$d) \quad \mu_n = 10^{4/33} \cdot 1000 = 1321.94$$

$$\begin{aligned}
 \beta_n &= \mu_n C_{ox} \left( \frac{W_n}{L_n} \right) = (1321.94)(1.44 \cdot 10^{-7}) \left( \frac{4000}{25} \right) \\
 &= 0.0305 \text{ A/V}^2
 \end{aligned}$$

$$V_{sat} = V_{GSn} - V_{Tn} = 2.3 - 0.992 = 1.308 \text{ V}$$

$$V_{DSn} = 1.9 > 1.308 \quad \text{saturation}$$

$$\begin{aligned}
 I_{Dn} &= \frac{1}{2} \beta_n (V_{sat})^2 = \frac{1}{2} (0.0305) (1.308)^2 \\
 &= 0.026 \text{ A}
 \end{aligned}$$